

RESEARCH PAPER

A dual-band crossover using cross-shaped microstrip line for small and large band ratios

IDURY SATYA KRISHNA, RUSAN KUMAR BARIK AND S. S. KARTHIKEYAN

A novel design of planar dual-band microstrip crossover operating at small and large frequency ratios is presented. These features of the proposed dual-band crossover are achieved by a cross-shaped transmission line. To obtain the dual-band characteristics, the required closed form design formulas are computed using the ABCD matrix method. Based on the design formulas, the realizable small and large band ratios are calculated as 1.65–2.14 and 4.1–8.76, respectively. To validate the computed band ratios, three examples of dual-band crossovers are presented. Finally, two prototypes of dual-band crossover working at smaller and larger frequency ratios are fabricated and tested. The fabricated dual-band crossovers exhibit good return loss and isolation of over 20 dB with minimal insertion loss.

Keywords: Passive components and circuits, Modeling, Simulation and characterizations of devices and circuits

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I. INTRODUCTION

The rapid advancements in modern wireless communication systems have made the devices smaller and the design more intricate. Due to the miniaturization in the size of the device there often is a need for two RF traces on a PCB (printed circuit board) to cross each other while maintaining a high degree of isolation. A microwave crossover is a device that allows intersection of two transmission lines while maintaining the desired isolation for the appropriate functioning of the device. Crossover finds major application in the design of Butler matrix for antenna array. Initially, crossovers were designed using three-dimensional (3D) structures such as bond wires, underpasses, via-holes, and air-bridges [1–3]. These designs not only presented a problem in fabrication, but also exhibited considerable return loss in the passband. Considering the drawbacks in 3D crossovers, the first planar microstrip crossover was developed using a two-section cascaded branch-line structure [4]. In [5], multi-section branch-line structures for the design of crossovers have been studied and bandwidths of crossover having up to seven cascaded branch-line sections has been reported. A microstrip coupler using double-ring structure has been presented [6]. In [7], the double-ring structure is extended by connecting arbitrary port-impedances to it. Crossover consisting of dual transmission lines of high impedance and different length has been proposed [8]. The concept of fractal geometry to design a

crossover using Sierpinski carpet patch has been demonstrated [9]. A highly compact wide-band crossover of dimension $1 \times 1 \text{ cm}^2$, designed by employing only lumped elements such as capacitor and inductor has been presented [10]. The design of crossover having wide-band response has been demonstrated in [11] by connecting a stop-band filter at each port of the proposed crossover. The band stop filter rejected the harmonics produced in the stop band of the crossover. A crossover having two-section branch-line coupler configuration with open-ended shunt stubs has been reported [12]. The crossovers reported in [3–12] operate at single frequency. But in the present day, microwave devices are required to function at multiple frequencies to support the current wireless standards. Several techniques to design a dual-band microwave crossover have been proposed in [13–21]. A two-section branch-line coupler is adopted to realize a dual-band crossover [13]. In [14], a crossover with a tri-section branch-line structure is proposed. To facilitate dual-band operation each branch arm of the structure is replaced by a dual-band structure such as π -section. The two-section branch-line has been used to design a microwave crossover in [15] without any additional stubs by just increasing the length of vertical transmission line by twice its original electrical length. The inner transmission line of this crossover is replaced by a T-shaped transmission line model [15]. Size reduction in a dual-band crossover by 59% in area as compared with conventional crossover has been shown in [16] by using composite right/left-handed material. A dual-band crossover has been designed in [17] using a cascaded structure as a replacement of the conventional branch arm. In [18], the crossover derived from cascaded branch-line couplers supporting flexible frequency ratios has been presented and the derived structure was later on named as window-shaped

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crossover. The window-shaped crossover was modified in [19] by replacing the inner transmission lines of the structure by an asymmetrical-shaped transmission line model. This design covered a wide range of frequency ratio from 2.2 to 6.89. The modified window-shape crossover was shown to be fundamentally incorrect in [20] due to the fact that a symmetrical transmission line cannot be replaced by an asymmetrical transmission line. A dual-band crossover operating for wide-band of frequency ratios has been reported [21]. This crossover was found to operate with good characteristics for the frequency ratio in between 1.35 and 4.8. In the existing literature, it is found that the crossovers can be realised only for a small range of frequency ratios.

In this paper, a new dual-band transmission line model is used to design dual-band crossovers, which can work at small as well as large frequency band ratios. The design parameters of the crossovers are obtained using closed-form equations derived analytically. Based on the design equations, the realizable small and large frequency band ratios are obtained as 1.65–2.14 and 4.1–8.76, respectively. To validate the proposed model, three examples of dual-band crossover are designed. Finally, two prototypes are fabricated and tested for the frequency ratios of 2.08 and 6. The measured return loss and isolation of the fabricated crossovers are better than 20 dB. The measured and full-wave simulated results are found in good agreement.

II. ANALYSIS OF THE DUAL-BAND TRANSMISSION LINE MODEL

The proposed topology of the dual-band cross-shaped microstrip line is depicted in Fig. 1. It is composed of two series transmission lines each of characteristic impedance Z_1 and electrical length θ_1 and two open-ended shunt stubs with same electrical length of θ_2 and different characteristic impedances of Z_2 and Z_3 are tapped at the center of the series lines. This dual-band microstrip line is used to replace the branch lines of the conventional crossover to produce dual-frequency characteristics. In order to compute the closed-form design equations, the ABCD matrix of the proposed topology is derived, by multiplying individual matrices of the

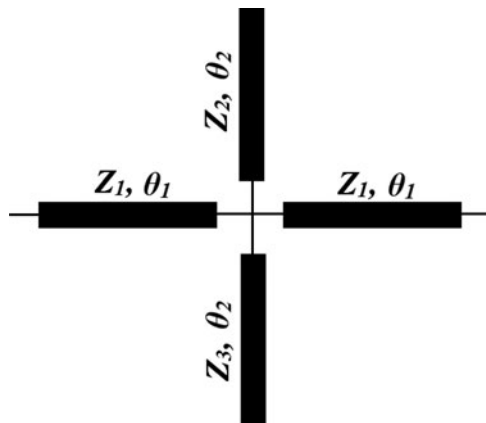


Fig. 1. The topology of the proposed dual-band cross-shaped transmission line.

transmission lines as follows:

$$\begin{bmatrix} A & B \\ C & D \end{bmatrix} = M_1 M_2 M_3 M_1, \tag{1}$$

where

$$M_1 = \begin{bmatrix} \cos \theta_1 & jZ_1 \sin \theta_1 \\ \frac{j \sin \theta_1}{Z_1} & \cos \theta_1 \end{bmatrix}, \tag{2a}$$

$$M_2 = \begin{bmatrix} 1 & 0 \\ \frac{j \tan \theta_2}{Z_2} & 1 \end{bmatrix}, \tag{2b}$$

$$M_3 = \begin{bmatrix} 1 & 0 \\ \frac{j \tan \theta_2}{Z_3} & 1 \end{bmatrix}. \tag{2c}$$

Each coefficient of the ABCD matrix in (1) can be written as:

$$A = D = \cos 2\theta_1 - \frac{Z_1}{2} \left(\frac{1}{Z_2} + \frac{1}{Z_3} \right) \sin 2\theta_1, \tag{3a}$$

$$B = jZ_1 \sin 2\theta_1 - jZ_1^2 \left(\frac{1}{Z_2} + \frac{1}{Z_3} \right) \sin^2 \theta_1 \tan \theta_2, \tag{3b}$$

$$C = j \frac{\sin 2\theta_1}{Z_1} + j \left(\frac{1}{Z_2} + \frac{1}{Z_3} \right) \cos^2 \theta_1 \tan \theta_2. \tag{3c}$$

The ABCD matrix of a conventional transmission line of impedance Z_T and electrical length θ_T can be given by:

$$\begin{bmatrix} A_T & B_T \\ C_T & D_T \end{bmatrix} = \begin{bmatrix} \cos \theta_T & jZ_T \sin \theta_T \\ \frac{j \sin \theta_T}{Z_T} & \cos \theta_T \end{bmatrix}. \tag{4}$$

To facilitate dual-band operation, the proposed structure is imposed to provide microstrip line with characteristic impedance of Z_T and electrical length of θ_T at two arbitrary frequencies, i.e. $A = \cos \theta_T$ and $B = Z_T \sin \theta_T$. Therefore, the equations (3a) and (3b) can be written as:

$$\cos 2\theta_1 - \frac{Z_1}{2} \left(\frac{1}{Z_2} + \frac{1}{Z_3} \right) \sin 2\theta_1 = \cos \theta_T, \tag{5a}$$

$$Z_1 \sin 2\theta_1 - Z_1^2 \left(\frac{1}{Z_2} + \frac{1}{Z_3} \right) \sin^2 \theta_1 \tan \theta_2 = Z_T \sin \theta_T. \tag{5b}$$

By solving the above equations, the closed-form design formulas for Z_1 and Z_2 can be obtained as:

$$Z_1 = \frac{Z_T}{\tan \theta_1}, \tag{6a}$$

$$Z_2 = \frac{Z_1}{2}(1 + k)\tan 2\theta_1 \tan \theta_2, \tag{6b}$$

where

$$k = \frac{Z_2}{Z_3}. \tag{7}$$

In order to obtain the dual-frequency operation, the magnitude of A_T and B_T should remain equal at two arbitrary frequencies. This implies the electrical length of the series arms and shunt stubs are computed as θ_1 and θ_2 at f_1 and $m\pi - \theta_1$ and $n\pi - \theta_2$ at f_2 , respectively. Hence, the design formulas of θ_1 and θ_2 can be given as:

$$\theta_1 = \frac{m\pi}{1 + p}, \tag{8a}$$

$$\theta_2 = \frac{n\pi}{1 + p}. \tag{8b}$$

The design guidelines for the proposed dual-band crossover working for smaller and larger frequency band ratios can be described as follows:

- (1) Select the characteristic impedance of Z_T and electrical length of θ_T of the conventional transmission line.
- (2) Set two arbitrary frequencies f_1 and f_2 .
- (3) Based on the desired frequencies, the electrical length of the series arms and shunt open stubs are computed from (8), by choosing appropriate values of m and n .
- (4) For compactness, the value of m is chosen as 1. The smaller and larger frequency ratios can be obtained by selecting $n = 2$ and 1, respectively.
- (5) Equation (6) and the values computed in former steps can be used to compute the values of Z_1 and Z_2 .
- (6) The physical parameters of the proposed structure can be evaluated at the first operating frequency f_1 .

In the present days, due to the inclusion of various wireless standards/applications such as GPS, Wi-Fi, Bluetooth, WLAN, WiMAX, and LTE, dual-band RF front-end components have found significant challenges to cover closely/widely spaced communication standards. Recently, many microstrip crossovers have been developed for dual-frequency operations, which exhibit smaller band ratios [13–16] and large/wide-band ratios [18, 21]. It is essential for a dual-band design to provide flexibility in terms of frequency ratio. Considering this issue, we propose a dual-frequency transmission line to cover commonly used communication standards for smaller as well as larger band ratios. The design curves to calculate the parameters of dual-band crossover operating at smaller and larger band ratios are shown in Figs 2 and 3, respectively. In both the plots, the value of k is varied to obtain realizable impedances for ease fabrication. Figure 2 shows the graphical solution for Z_1 and Z_2 versus frequency ratios (P) by choosing $m = 1$ and $n = 2$. Therefore, this solution can be used to implement dual-band crossover for smaller frequency ratios. From the plot, it is computed that the range of ratio from 1.65 to 2.14 can be devised, assuming the limitation of practical realizable impedance for microstrip technology as 20–150 Ω . Similarly, the plot of Z_1 and Z_2 versus

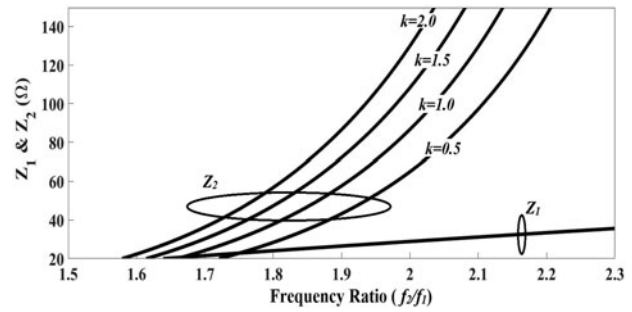


Fig. 2. Design curve of Z_1 and Z_2 as function of frequency ratio (f_2/f_1) for smaller band ratio.

frequency ratio (P) by choosing $m = 1$ and $n = 1$ is depicted in Fig. 3. From the graph, the range of ratio is calculated as 4.1 to 8.76, considering the same limitation of microstrip technology.

III. DESIGN OF DUAL-BAND CROSSOVER

A conventional two-section branch-line coupler is modified to work as a crossover [5]. The configuration of the conventional crossover is shown in Fig. 4. The required characteristic impedances and electrical lengths of the crossover are obtained as $Z_a = Z_b = Z_c = 50 \Omega$ and $\theta = 90^\circ$. The proposed dual-band crossover is developed by using a cross-shaped transmission line in the place of the quarter wavelength branch-arm of

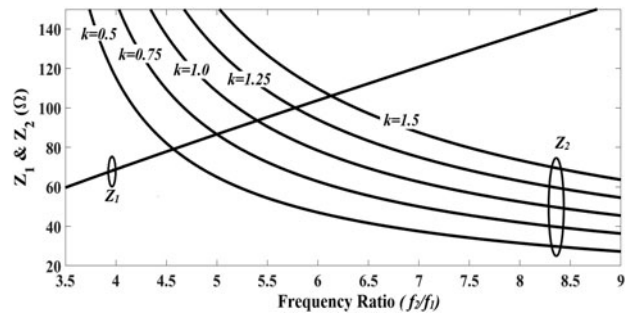


Fig. 3. Design curve of Z_1 and Z_2 as function of frequency ratio (f_2/f_1) for different values of k .

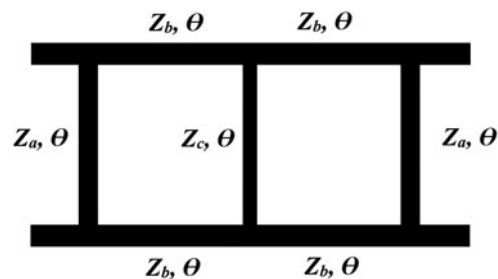


Fig. 4. Schematic diagram of a two-section branch-line conventional crossover.

Table 1. Design parameters of the proposed crossover for different frequency bands.

Designs	Operating frequency (GHz)	Frequency ratio (P)	Z_1 (Ω)	θ_1 (deg)	Z_2 (Ω)	θ_2 (deg)	Z_3 (Ω)
Type A	0.9/1.8	2	28.87	60	82.87	120	91.41
Type B	1/4.1	4.1	70.63	35.294	134.8	35.294	149.8
Type C	0.9/7.2	8	137.4	20	39.86	20	44.29
*Type X	2.4/5.0 [†]	2.08	30.8	58.37	133.21	116.75	111
*Type Y	0.9/5.4 [‡]	6	103.8	25.71	47	25.71	94.05

*Design parameters of the fabricated dual-band crossovers.
[†]Type X (smaller frequency ratio).
[‡]Type Y (larger frequency ratio).

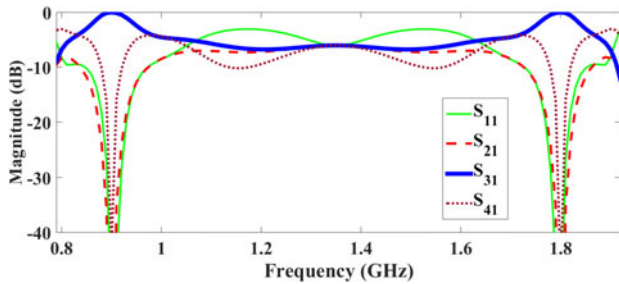


Fig. 5. Frequency response of the crossover operating at 0.9 and 1.8 GHz (frequency ratio = 2).

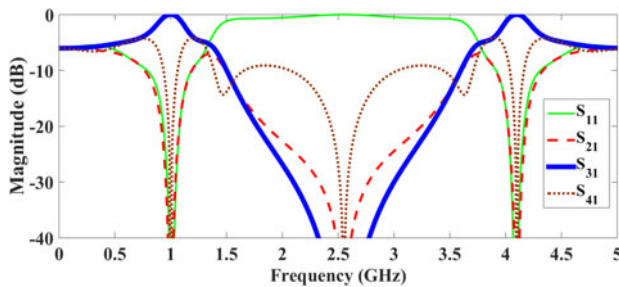


Fig. 6. Frequency response of the crossover operating at 1 and 4.1 GHz (frequency ratio = 4.1).

the conventional crossover. To support the theoretical analysis in Section II, three examples of dual-band crossovers are designed at different frequency ratios. Finally, two prototype of dual-band crossover are fabricated and demonstrated.

The design parameters for all the examples are summarized in Table 1. For example, type A crossover is designed for small

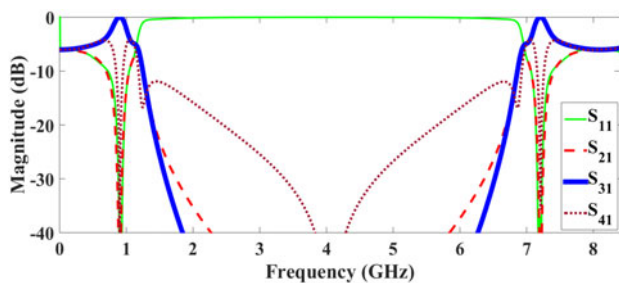


Fig. 7. Frequency response of the crossover operating at 0.9 and 7.2 GHz (frequency ratio = 8).

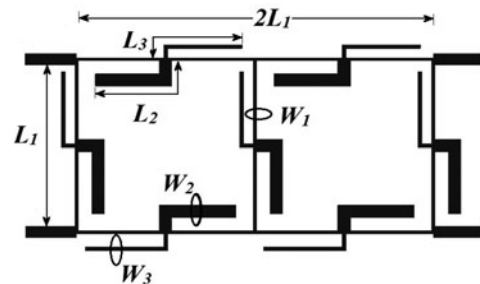


Fig. 8. Final Layout of the proposed dual-band crossovers.

band ratio, i.e. $P = 2$. The simulated result of the dual-band crossover operating at the global system for mobile communications (GSM) lower (0.9 GHz) and upper (1.8 GHz) bands is depicted in Fig. 5. Similarly, types B and C crossovers are developed for the frequency ratios of 4.1 and 8, respectively. Figures 6 and 7 show the circuit simulation results for types B and C crossovers, respectively. It is revealed that both channels are well isolated by over -25 dB in all examples. With the ideal transmission line, insertion losses and return losses are of 0 dB and well below -25 dB at two operating frequencies for all designs. For these designs, it is clear that the proposed dual-frequency transmission line is suitable for smaller as well as larger frequency band ratios.

IV. MEASUREMENT AND ANALYSIS OF THE PROTOTYPE

To validate the theoretical analysis, two prototypes of dual-band crossover working for smaller (type X) and larger (type Y) frequency ratios are designed, fabricated and tested. The design parameters of the dual-band microstrip line for types X and Y are illustrated in Table 1. The type X is operating at 2.4 and 5 GHz, whereas type Y is operating at 0.9 and 5.4 GHz. The final physical layout of the dual-band crossover is shown in Fig. 8. The dimensions are computed

Table 2. Computed dimensions of the physical layout for types X and Y.

Design	L_1 (mm)	W_1 (mm)	L_2 (mm)	W_2 (mm)	L_3 (mm)	W_3 (mm)
Type X	28.2	4.58	30.34	0.32	30.25	0.51
Type Y	35.16	0.63	20.55	2.47	18.45	0.7

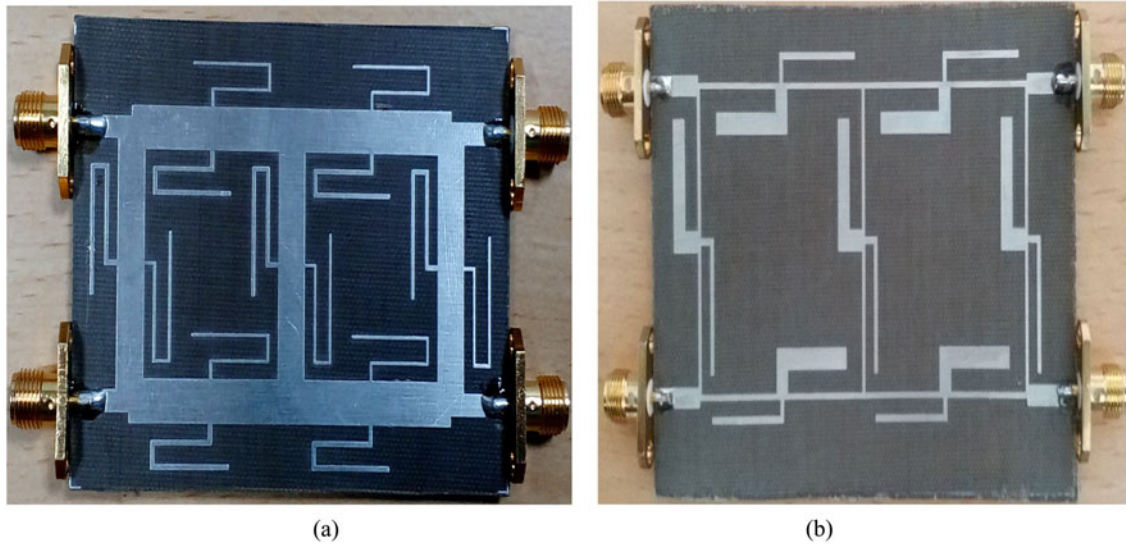


Fig. 9. Photograph of the fabricated dual-band crossovers. (a) Type X and (b) type Y.

and depicted in Table 2. The circuit size of the proposed crossovers is $0.477\lambda_g \times 0.68\lambda_g$ or equivalently, $42.2 \times 60.98 \text{ mm}^2$ for type X and $0.143\lambda_g \times 0.286\lambda_g$ or equivalently, $35.16 \times 70.32 \text{ mm}^2$ for type Y, here λ_g is the guided wavelength at f_1 . The proposed dual-band crossovers are fabricated on a RT Duroid 5870 substrate of thickness 0.787 mm, with a dielectric constant $\epsilon_r = 2.33$. The fabricated prototypes of dual-band crossover are presented in Fig. 9.

The measurements of the fabricated crossovers are carried out using Rohde Schwarz Network Analyser. The return loss of the crossovers at the design frequencies are above 20 dB. The two signal paths are well isolated from each other by

$>20 \text{ dB}$ at all the operating frequencies for both the prototypes. Insertion losses at f_1/f_2 are obtained as 0.33/0.72 dB for type X and 0.62/0.67 dB for type Y. The measured and simulated frequency responses of the crossovers are shown in Fig. 10 (type X) and Fig. 11 (type Y). Frequency responses depict good agreement between simulated and measured results, and both exhibit similar characteristics. The bandwidth of the fabricated prototypes is greater than 50 MHz at all operating frequencies, which is suitable for most of the applications. Table 3 shows the comparison between the proposed crossover and the current state-of-the-art crossovers.

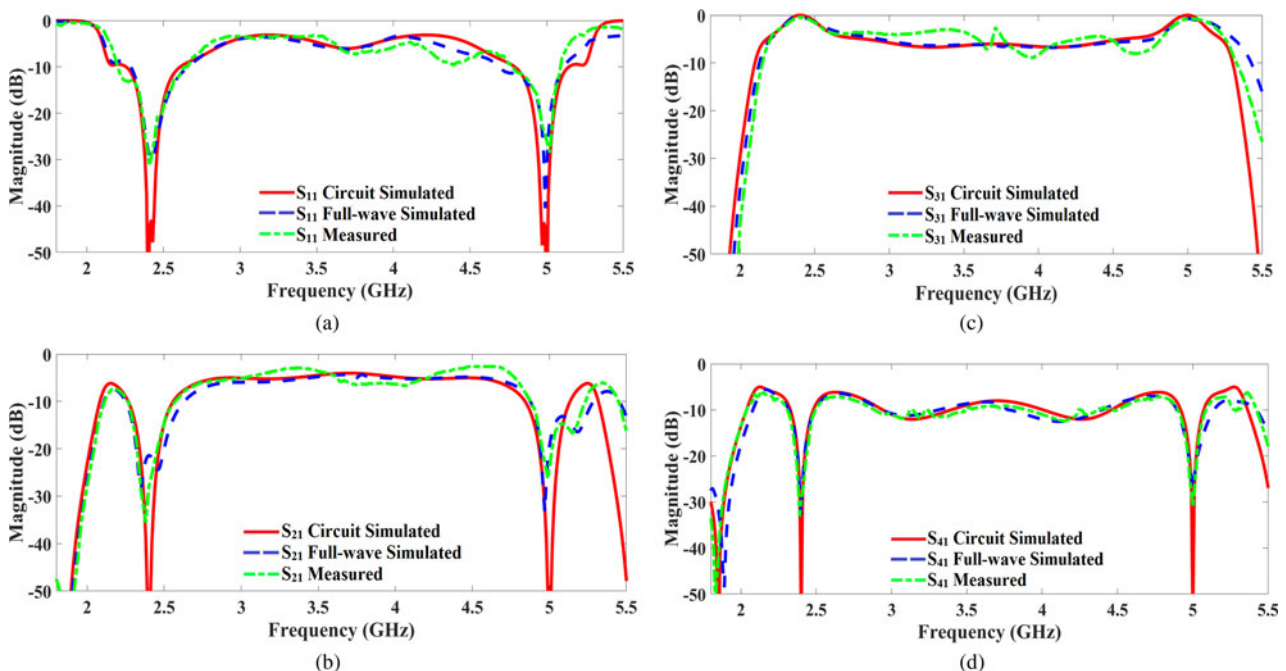


Fig. 10. Frequency response of the crossover depicting (a) return loss, (b) isolation (S_{21}), (c) insertion loss, and (d) isolation (S_{41}).

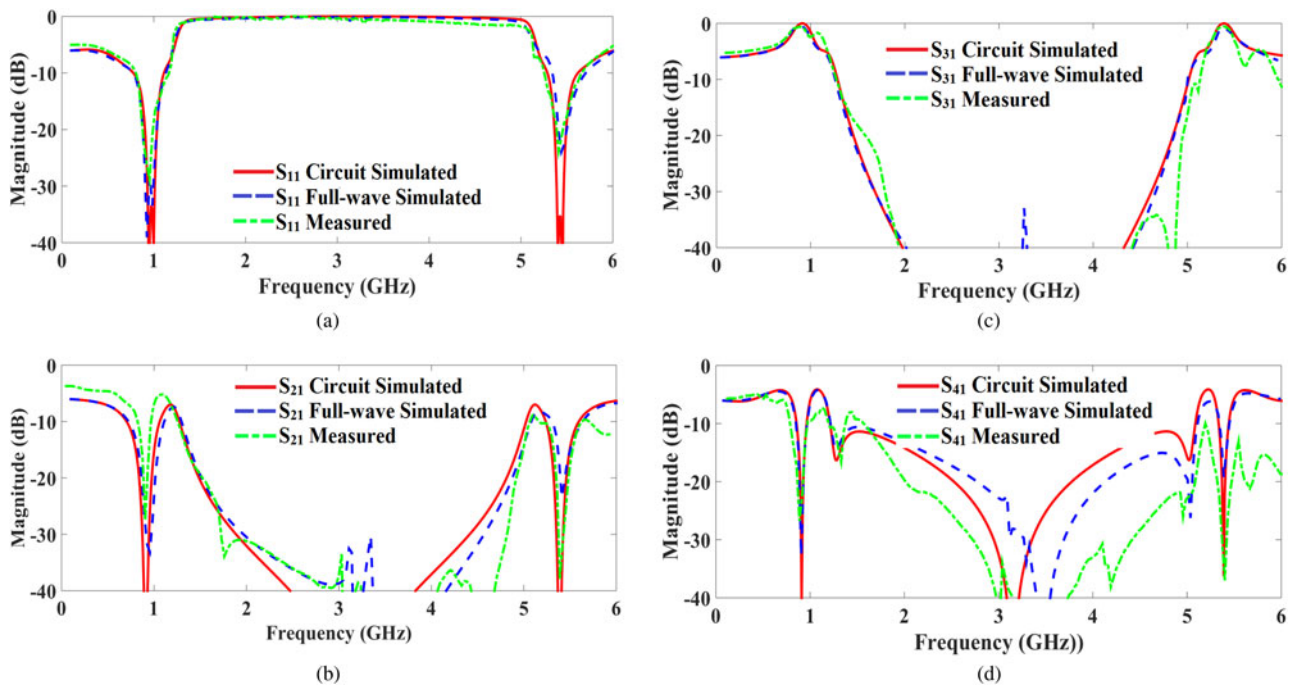


Fig. 11. Frequency response of the crossover depicting (a) return loss, (b) isolation (S_{21}), (c) insertion loss, and (d) isolation (S_{41}).

Table 3. Comparison with the current state-of-the-art crossovers.

Ref	Configuration	Passband frequency (GHz)	Operating frequency ratio	Bandwidth (MHz)	Insertion loss (dB)	Isolation loss (dB)	Return Loss (dB)
[13]	Two section branch-line hybrid	0.9/2.45	1.5–3.0	47.5/34.6 ^a	0.7/1.35	>20/>20	>20/>20
[14]	Three section branch-line hybrid	1/2	1.5–3.0	57/110 ^a	0.55/0.75	>20/>20	>20/>20
[15]	Two section branch-line hybrid	1/1.8	1.45–1.9	56.3/37.47 ^a	0.3/0.48	>20/>20	>20/>20
[15]	Two section branch-line hybrid with T-shaped stubs	1/2.3	2.13–2.35	72/60 ^a	0.31/0.57	>20/>20	>20/>20
[16]	Composite left/right-handed materials	0.9/2.45	Not reported	Not reported	1.34/1.26	>20/>20	>20/>20
[18]	Window-shaped crossover	1/2.3	1.6–4	20/80 ^a	0.38/0.98	>20/>20	>20/>20
[19]	Window-shaped crossover with π -shaped model	0.5/1.5	2–7	21/23 ^a	0.45/0.75	>20/>20	>20/>20
[21]	Two section branch-line hybrid with T-shaped stubs	1/4	1.35–4.8	20/20 ^a	0.4/1.1	>20/>18	>20/>20
This work	Two section branch-line hybrid with cross-shaped stubs	2.4/5*	1.65–2.14, 4.1–8.76	70/50, 60/60	0.33/0.72, 0.62/0.67	>20/>20, >20/>20	>20/>20, >20/>20

*Type X (smaller frequency ratio)

†Type Y (larger frequency ratio).

^aEstimated from the figure given in [14–21], considering –20 dB reference level for S_{11} , S_{21} , and S_{41} .

IV. CONCLUSION

In this paper, the design of dual-band crossovers working at smaller and larger frequency ratios are presented. The derived smaller and larger band ratios for the proposed cross-shaped crossover are 1.65–2.14 and 4.1–8.76, respectively. The proposed crossover uses the cross-shaped transmission line for dual-band operation. The simulated and measured results indicate isolation and return loss above 20 dB for both the fabricated prototypes. The insertion loss in diagonal ports of each fabricated prototype is observed as <0.72 dB at the design frequency. The proposed cross-shaped structure and the design methodology described in this paper can be used for design of dual-band branch-line and rat-race coupler.

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